SWITCHMODE™ Power Rectifier 45 V, 40 A

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- Guard-Ring for Stress Protection
- AEC-Q101 Qualified and PPAP Capable
- NRVBB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free and are RoHS Compliant*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube for TO-220

MAXIMUM RATINGS

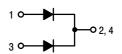
Please See the Table on the Following Page



ON Semiconductor®

http://onsemi.com

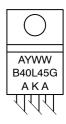
SCHOTTKY BARRIER RECTIFIERS 40 AMPERES, 45 VOLTS

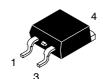


MARKING DIAGRAMS



TO-220 CASE 221A PLASTIC





D²PAK CASE 418B STYLE 3



B40L45 = Device Code

A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Device
AKA = Polarity Designator

ORDERING INFORMATION

Device	Package	Shipping [†]
MBR40L45CTG	TO-220 (Pb-Free)	50 Units/Rail
NRVBB40L45CTT4G	D2PAK (Pb-Free)	800 /Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V_R) $T_C = 145^{\circ}C$	I _{F(AV)}	20	Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz)	I _{FRM}	40	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	200	Α
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Storage Temperature	T _{stg}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V
HERMAL CHARACTERISTICS	•	•	
Maximum Thermal Resistance – Junction–to–Case	$R_{ hetaJC}$	1.9	°C/W

Maximum Thermal Resistance			°C/W
- Junction-to-Case	$R_{ heta JC}$	1.9	
Junction-to-Ambient	$R_{ heta JA}$	72.9	

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

$\label{eq:maximum instantaneous Forward} \begin{tabular}{l} $(I_F = 20 \ A, T_C = 25^\circ C)$ \\ $(I_F = 20 \ A, T_C = 125^\circ C)$ \\ $(I_F = 40 \ A, T_C = 25^\circ C)$ \\ $(I_F = 40 \ A, T_C = 125^\circ C)$ \\ \end{tabular}$	Voltage (Note 2)	VF	0.50 0.48 0.63 0.68	>
Maximum Instantaneous Reverse (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	,	İR	1.2 275	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

^{2.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤2.0%.

TYPICAL CHARACTERISTICS

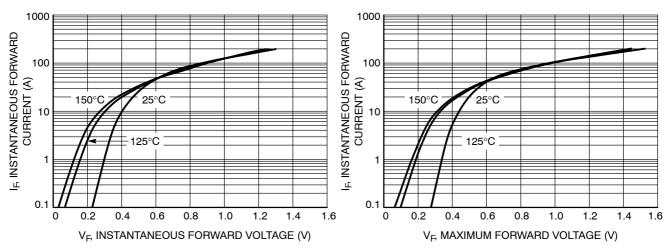


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

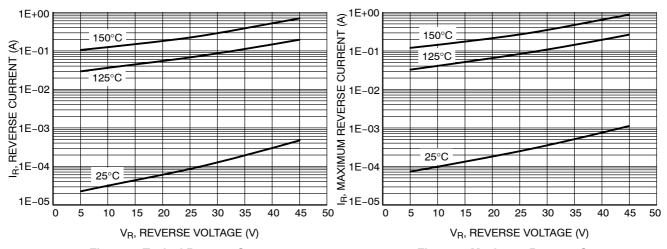


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

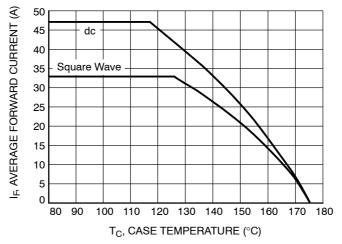


Figure 5. Current Derating for MBR40L45CTG

TYPICAL CHARACTERISTICS

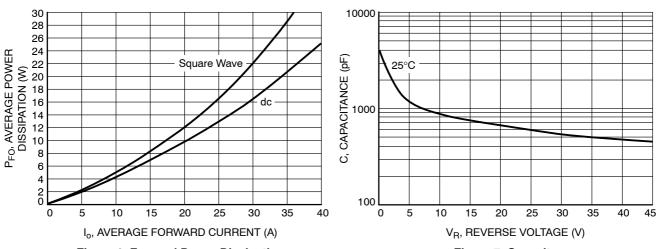


Figure 6. Forward Power Dissipation

Figure 7. Capacitance

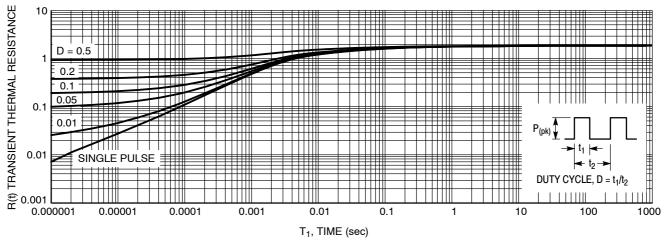
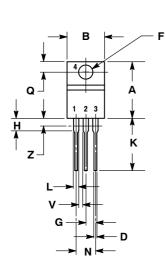
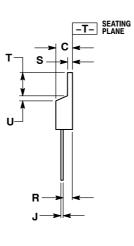


Figure 8. Thermal Response Junction-to-Case for MBR40L45CTG

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





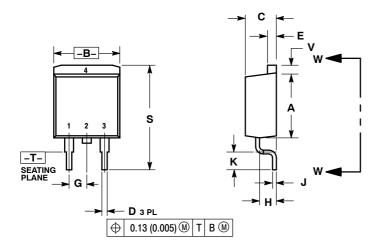
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

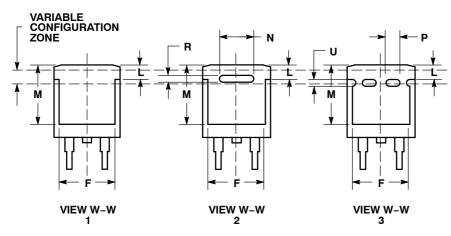
	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
 PIN 1. ANODE
 2. CATHODE
 3. ANODE
 4. CATHODE

PACKAGE DIMENSIONS

D²PAK 3 CASE 418B-04 **ISSUE J**



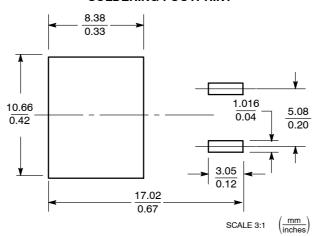


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.035	0.51	0.89	
E	0.045	0.055	1.14	1.40	
F	0.310	0.350	7.87	8.89	
G	0.100	BSC	2.54 BSC		
Н	0.080	0.110	2.03	2.79	
J	0.018	0.025	0.46	0.64	
K	0.090	0.110	2.29	2.79	
L	0.052	0.072	1.32	1.83	
М	0.280	0.320	7.11	8.13	
N	0.197 REF		5.00 REF		
Р	0.079 REF		2.00 REF		
R	0.039 REF		0.99 REF		
S	0.575	0.625	14.60	15.88	
V	0.045	0.055	1.14	1.40	

- STYLE 3: PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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